

KA78LXXA/KA78L05AA

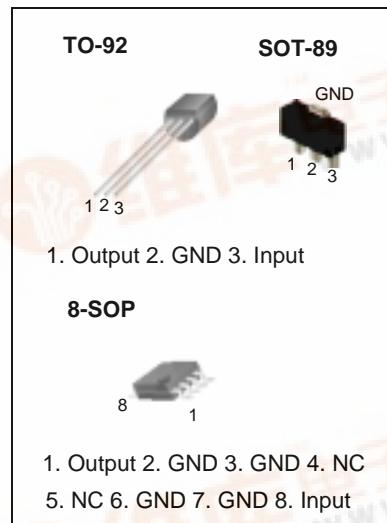
3-Terminal 0.1A Positive Voltage Regulator

Features

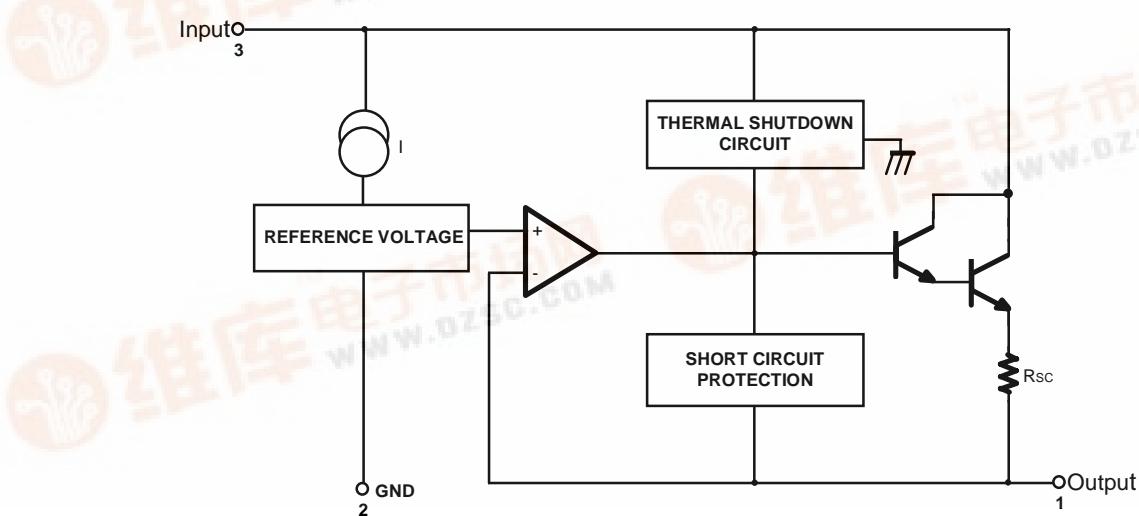
- Maximum Output Current of 100mA
- Output Voltage of 5V, 6V, 8V, 9V, 10V, 12V, 15V, 18V and 24V
- Thermal Overload Protection
- Short Circuit Current Limiting
- Output Voltage Offered in $\pm 5\%$ Tolerance

Description

The KA78LXXA/KA78L05AA series of fixed voltage monolithic integrated circuit voltage regulators are suitable for application that required supply current up to 100mA.



Internal Block Diagram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage (for $V_O = 5V, 8V$) (for $V_O = 12V$ to $18V$) (for $V_O = 24V$)	V_I	30 35 40	V
Operating Junction Temperature Range	T_J	0 ~ +150	°C
Storage Temperature Range	T_{STG}	-65 ~ +150	°C

Electrical Characteristics(KA78L05A)

($V_I = 10V$, $I_O = 40mA$, $0^\circ C \leq T_J \leq 125^\circ C$, $C_I = 0.33\mu F$, $C_O = 0.1\mu F$, unless otherwise specified. (Note1)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	$T_J = 25^\circ C$		4.8	5.0	5.2	V
Line Regulation (Note1)	ΔV_O	$T_J = 25^\circ C$	$7V \leq V_I \leq 20V$	-	8	150	mV
			$8V \leq V_I \leq 20V$	-	6	100	mV
Load Regulation (Note1)	ΔV_O	$T_J = 25^\circ C$	$1mA \leq I_O \leq 100mA$	-	11	60	mV
			$1mA \leq I_O \leq 40mA$	-	5.0	30	mV
Output Voltage	V_O	$7V \leq V_I \leq 20V$	$1mA \leq I_O \leq 40mA$	-	-	5.25	V
		$7V \leq V_I \leq V_{MAX}$ (Note 2)	$1mA \leq I_O \leq 70mA$	4.75	-	5.25	V
Quiescent Current	I_Q	$T_J = 25^\circ C$		-	2.0	5.5	mA
Quiescent Current Change	with line	ΔI_Q	$8V \leq V_I \leq 20V$		-	-	1.5 mA
	with load	ΔI_Q	$1mA \leq I_O \leq 40 mA$		-	-	0.1 mA
Output Noise Voltage	V_N	$T_A = 25^\circ C$, $10Hz \leq f \leq 100kHz$		-	40	-	$\mu V/V_o$
Temperature Coefficient of V_O	$\Delta V_O/\Delta T$	$I_O = 5mA$		-	-0.65	-	$mV/^\circ C$
Ripple Rejection	RR	$f = 120Hz$, $8V \leq V_I \leq 18V$, $T_J = 25^\circ C$		41	80	-	dB
Dropout Voltage	V_D	$T_J = 25^\circ C$		-	1.7	-	V

Note:

1. The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.
2. Power dissipation $P_D \leq 0.75W$.

Electrical Characteristics(KA78L06A) (Continued)

(VI = 12V, IO = 40mA, 0°C ≤ TJ ≤ 125°C, CI = 0.33µF, CO = 0.1µF, unless otherwise specified. (Note 1)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	VO	TJ = 25°C		5.75	6.0	6.25	V
Line Regulation (Note1)	ΔVO	TJ = 25°C	8.5V ≤ VI ≤ 20V	-	64	175	mV
			9V ≤ VI ≤ 20V	-	54	125	mV
Load Regulation (Note1)	ΔVO	TJ = 25°C	1mA ≤ IO ≤ 100mA	-	12.8	80	mV
			1mA ≤ IO ≤ 70mA	-	5.8	40	mV
Output Voltage	VO	8.5 ≤ VI ≤ 20V, 1mA ≤ IO ≤ 40mA		5.7	-	6.3	V
		8.5 ≤ VI ≤ VMAX(Note), 1mA ≤ IO ≤ 70mA		5.7	-	6.3	V
Quiescent Current	IQ	TJ = 25°C		-	-	5.5	mA
		TJ = 125°C		-	3.9	6.0	mA
Quiescent Current Change	with line	ΔIQ	9 ≤ VI ≤ 20V		-	-	1.5 mA
	with load	ΔIQ	1mA ≤ IO ≤ 40mA		-	-	0.1 mA
Output Noise Voltage	VN	TA = 25°C, 10Hz ≤ f ≤ 100kHz		-	40	-	µV/Vo
Temperature Coefficient of VO	ΔVO/ΔT	IO = 5mA		-	0.75	-	mV/ °C
Ripple Rejection	RR	f = 120Hz, 10V ≤ VI ≤ 20V, TJ = 25°C		40	46	-	dB
Dropout Voltage	VD	TJ = 25°C		-	1.7	-	V

Note:

1. The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.
2. Power dissipation PD ≤ 0.75W.

Electrical Characteristics(KA78L08A) (Continued)

(VI = 14V, IO = 40mA, 0°C ≤ TJ ≤ 125°C, CI = 0.33µF, CO = 0.1µF, unless otherwise specified. (Note 1)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	VO	TJ = 25°C		7.7	8.0	8.3	V
Line Regulation (Note1)	ΔVO	TJ = 25°C	10.5V ≤ VI ≤ 23V	-	10	175	mV
			11V ≤ VI ≤ 23V	-	8	125	mV
Load Regulation (Note1)	ΔVO	TJ = 25°C	1mA ≤ IO ≤ 100mA	-	15	80	mV
			1mA ≤ IO ≤ 40mA	-	8.0	40	mV
Output Voltage	VO	10.5V ≤ VI ≤ 23V	1mA ≤ IO ≤ 40mA	7.6	-	8.4	V
		10.5V ≤ VI ≤ VMAX (Note 2)	1mA ≤ IO ≤ 70mA	7.6	-	8.4	V
Quiescent Current	IQ	TJ = 25°C		-	2.0	5.5	mA
Quiescent Current Change	with line	ΔIQ	11V ≤ VI ≤ 23V		-	-	1.5 mA
	with load	ΔIQ	1mA ≤ IO ≤ 40mA		-	-	0.1 mA
Output Noise Voltage	VN	TA = 25°C, 10Hz ≤ f ≤ 100kHz		-	60	-	µV/Vo
Temperature Coefficient of VO	ΔVO/ΔT	IO = 5mA		-	-0.8	-	mV/°C
Ripple Rejection	RR	f = 120Hz, 11V ≤ VI ≤ 21V, TJ = 25°C		39	70	-	dB
Dropout Voltage	VD	TJ = 25°C		-	1.7	-	V

Note:

1. The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.
2. Power dissipation PD ≤ 0.75W.

Electrical Characteristics(KA78L09A) (Continued)

($V_I = 15V$, $I_O = 40mA$, $0^\circ C \leq T_J \leq 125^\circ C$, $C_I = 0.33\mu F$, $C_O = 0.1\mu F$, unless otherwise specified. (Note 1)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	$T_J = 25^\circ C$		8.64	9.0	9.36	V
Line Regulation (Note1)	ΔV_O	$T_J = 25^\circ C$	$11.5V \leq V_I \leq 24V$	-	90	200	mV
			$13V \leq V_I \leq 24V$	-	100	150	mV
Load Regulation (Note1)	ΔV_O	$T_J = 25^\circ C$	$1mA \leq I_O \leq 100mA$	-	20	90	mV
			$1mA \leq I_O \leq 40mA$	-	10	45	mV
Output Voltage	V_O	$11.5V \leq V_I \leq 24V$	$1mA \leq I_O \leq 40mA$	8.55	-	9.45	V
		$11.5V \leq V_I \leq V_{MAX}$ (Note 2)	$1mA \leq I_O \leq 70mA$	8.55	-	9.45	V
Quiescent Current	I_Q	$T_J = 25^\circ C$		-	2.1	6.0	mA
Quiescent Current Change	with line	ΔI_Q	$13V \leq V_I \leq 24V$		-	-	1.5 mA
	with load	ΔI_Q	$1mA \leq I_O \leq 40mA$		-	-	0.1 mA
Output Noise Voltage	V_N	$T_A = 25^\circ C$, $10Hz \leq f \leq 100kHz$		-	70	-	$\mu V/V_O$
Temperature Coefficient of V_O	$\Delta V_O/\Delta T$	$I_O = 5mA$		-	-0.9	-	$mV/^\circ C$
Ripple Rejection	RR	$f = 120Hz$, $12V \leq V_I \leq 22V$, $T_J = 25^\circ C$		38	44	-	dB
Dropout Voltage	V_D	$T_J = 25^\circ C$		-	1.7	-	V

Note:

1. The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.
2. Power dissipation $P_D \leq 0.75W$.

Electrical Characteristics(KA78L10A) (Continued)

(VI = 16V, IO = 40mA, 0 °C ≤ TJ ≤ 125 °C, CI = 0.33 µF, CO = 0.1µF, unless otherwise specified. (Note 1)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit	
Output Voltage	VO	TJ = 25°C		9.6	10.0	10.4	V	
Line Regulation (Note1)	ΔVO	TJ = 25°C	12.5 ≤ VI ≤ 25V	-	100	220	mV	
			14V ≤ VI ≤ 25V	-	100	170	mV	
Load Regulation (Note1)	ΔVO	TJ = 25°C	1mA ≤ IO ≤ 100mA	-	20	94	mV	
			1mA ≤ IO ≤ 70mA	-	10	47	mV	
Output Voltage	VO	12.5V ≤ VI ≤ 25V, 1mA ≤ IO ≤ 40mA		9.5	-	10.5	V	
		12.5V ≤ VI ≤ VMAX (Note2) 1mA ≤ IO ≤ 70mA		9.5	-	10.5		
Quiescent Current	IQ	TJ = 25°C		-	-	6.0	mA	
		TJ = 125°C		-	4.2	6.5		
Quiescent Current Change	with line	ΔIQ	12.5 ≤ VI ≤ 25V		-	-	1.5 mA	
	with load	ΔIQ	1mA ≤ IO ≤ 40mA		-	-	0.1 mA	
Output Noise Voltage		VN	TA = 25°C, 10Hz ≤ f ≤ 100kHz		-	74	-	µV/Vo
Temperature Coefficient of VO		ΔVO/ΔT	IO = 5mA		-	0.95	-	mV/ °C
Ripple Rejection		RR	f = 120Hz, 15V ≤ VI ≤ 25V, TJ = 25°C		38	43	-	dB
Dropout Voltage		VD	TJ = 25°C		-	1.7	-	V

Notes:

1. The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.
2. Power dissipation PD ≤ 0.75W.

Electrical Characteristics(KA78L12A) (Continued)

($V_I = 19V$, $I_O = 40mA$, $0^\circ C \leq T_J \leq 125^\circ C$, $C_I = 0.33 \mu F$, $C_O = 0.1 \mu F$, unless otherwise specified. (Note 1)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	$T_J = 25^\circ C$		11.5	12	12.5	V
Line Regulation (Note1)	ΔV_O	$T_J = 25^\circ C$	14.5V $\leq V_I \leq 27V$	-	20	250	mV
			16V $\leq V_I \leq 27V$	-	15	200	mV
Load Regulation (Note1)	ΔV_O	$T_J = 25^\circ C$	1mA $\leq I_O \leq 100mA$	-	20	100	mV
			1mA $\leq I_O \leq 40mA$	-	10	50	mV
Output Voltage	V_O	14.5V $\leq V_I \leq 27V$	1mA $\leq I_O \leq 40mA$	11.4	-	12.6	V
		14.5V $\leq V_I \leq V_{MAX}$ (Note 2)	1mA $\leq I_O \leq 70mA$	11.4	-	12.6	V
Quiescent Current	I_Q	$T_J = 25^\circ C$		-	2.1	6.0	mA
Quiescent Current Change	with line	ΔI_Q	16V $\leq V_I \leq 27V$		-	-	1.5 mA
	with load	ΔI_Q	1mA $\leq I_O \leq 40mA$		-	-	0.1 mA
Output Noise Voltage	V_N	$T_A = 25^\circ C$, 10Hz $\leq f \leq 100kHz$		-	80	-	$\mu V/V_O$
Temperature Coefficient of V_O	$\Delta V_O/\Delta T$	$I_O = 5mA$		-	-1.0	-	$mV/^\circ C$
Ripple Rejection	RR	$f = 120Hz$, 15V $\leq V_I \leq 25V$, $T_J = 25^\circ C$		37	65	-	dB
Dropout Voltage	V_D	$T_J = 25^\circ C$		-	1.7	-	V

Note:

1. The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.
2. Power dissipation $P_D \leq 0.75W$.

Electrical Characteristics(KA78L15A) (Continued)

(VI = 23V, IO = 40mA, 0°C ≤ TJ ≤ 125°C, CI = 0.33 µF, CO = 0.1µF, unless otherwise specified. (Note 1)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	VO	TJ = 25°C		14.4	15	15.6	V
Line Regulation (Note1)	ΔVO	TJ = 25°C	17.5V ≤ VI ≤ 30V	-	25	300	mV
			20V ≤ VI ≤ 30V	-	20	250	mV
Load Regulation (Note1)	ΔVO	TJ = 25°C	1mA ≤ IO ≤ 100mA	-	25	150	mV
			1mA ≤ IO ≤ 40mA	-	12	75	mV
Output Voltage	VO	17.5V ≤ VI ≤ 30V	1mA ≤ IO ≤ 40mA	14.25	-	15.75	V
		17.5V ≤ VI ≤ VMAX (Note 2)	1mA ≤ IO ≤ 70mA	14.25	-	15.75	V
Quiescent Current	IQ	TJ = 25°C		-	2.1	6.0	mA
Quiescent Current Change	with line	ΔIQ	20V ≤ VI ≤ 30V	-	-	1.5	mA
	with load	ΔIQ	1mA ≤ IO ≤ 40mA	-	-	0.1	mA
Output Noise Voltage	VN	TA = 25°C, 10Hz ≤ f ≤ 100kHz		-	90	-	µV/Vo
Temperature Coefficient of VO	ΔVO/ΔT	IO = 5mA		-	-1.3	-	mV/°C
Ripple Rejection	RR	f = 120Hz, 18.5V ≤ VI ≤ 28.5V, TJ = 25°C		34	60	-	dB
Dropout Voltage	VD	TJ = 25°C		-	1.7	-	V

Note:

1. The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.
2. Power dissipation PD ≤ 0.75W.

Electrical Characteristics(KA78L18A) (Continued)

($V_I = 27V$, $I_O = 40mA$, $0^\circ C \leq T_J \leq 125^\circ C$, $C_I = 0.33 \mu F$, $C_O = 0.1 \mu F$, unless otherwise specified. (Note 1)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	$T_J = 25^\circ C$		17.3	18	18.7	V
Line Regulation (Note1)	ΔV_O	$T_J = 25^\circ C$	21V $\leq V_I \leq 33V$	-	145	300	mV
			22V $\leq V_I \leq 33V$	-	135	250	mV
Load Regulation (Note1)	ΔV_O	$T_J = 25^\circ C$	1mA $\leq I_O \leq 100mA$	-	30	170	mV
			1mA $\leq I_O \leq 40mA$	-	15	85	mV
Output Voltage	V_O	21V $\leq V_I \leq 33V$	1mA $\leq I_O \leq 40mA$	17.1	-	18.9	V
		21V $\leq V_I \leq V_{MAX}$ (Note 2)	1mA $\leq I_O \leq 70mA$	17.1	-	18.9	V
Quiescent Current	I_Q	$T_J = 25^\circ C$		-	2.2	6.0	mA
Quiescent Current Change	with line	ΔI_Q	21V $\leq V_I \leq 33V$		-	-	1.5 mA
	with load	ΔI_Q	1mA $\leq I_O \leq 40mA$		-	-	0.1 mA
Output Noise Voltage	V_N	$T_A = 25^\circ C$, $10Hz \leq f \leq 100kHz$		-	150	-	$\mu V/V_O$
Temperature Coefficient of V_O	$\Delta V_O/\Delta T$	$I_O = 5mA$		-	-1.8	-	$mV/^\circ C$
Ripple Rejection	RR	$f = 120Hz$, $23V \leq V_I \leq 33V$, $T_J = 25^\circ C$		34	48	-	dB
Dropout Voltage	V_D	$T_J = 25^\circ C$		-	1.7	-	V

Note:

1. The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.
2. Power dissipation $P_D \leq 0.75W$.

Electrical Characteristics(KA78L24A) (Continued)

(VI = 33V, IO = 40mA, 0°C ≤ TJ ≤ 125°C, CI = 0.33 µF, CO = 0.1µF, unless otherwise specified. (Note 1)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	VO	TJ = 25°C		23	24	25	V
Line Regulation (Note1)	ΔVO	TJ = 25°C	27V ≤ VI ≤ 38V	-	160	300	mV
			28V ≤ VI ≤ 38V	-	150	250	mV
Load Regulation (Note1)	ΔVO	TJ = 25°C	1mA ≤ IO ≤ 100mA	-	40	200	mV
			1mA ≤ IO ≤ 40mA	-	20	100	mV
Output Voltage	VO	27V ≤ VI ≤ 38V	1mA ≤ IO ≤ 40mA	22.8	-	25.2	V
		27V ≤ VI ≤ VMAX (Note 2)	1mA ≤ IO ≤ 70mA	22.8	-	25.2	V
Quiescent Current	IQ	TJ = 25°C		-	2.2	6.0	mA
Quiescent Current Change	with line	ΔIQ	28V ≤ VI ≤ 38V		-	-	1.5 mA
	with load	ΔIQ	1mA ≤ IO ≤ 40mA		-	-	0.1 mA
Output Noise Voltage	VN	TA = 25°C, 10Hz ≤ f ≤ 100kHz		-	200	-	µV/Vo
Temperature Coefficient of VO	ΔVO/ΔT	IO = 5mA		-	-2.0	-	mV/°C
Ripple Rejection	RR	f = 120Hz, 28V ≤ VI ≤ 38V, TJ = 25°C		34	45	-	dB
Dropout Voltage	VD	TJ = 25°C		-	1.7	-	V

Note:

1. The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.
2. Power dissipation PD ≤ 0.75W.

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage (for $V_O = 5V, 8V$) (for $V_O = 12V$ to $18V$) (for $V_O = 24V$)	V_I	30	V
		35	V
		40	V
Operating Junction Temperature Range	T_J	0 ~ +150	°C
Storage Temperature Range	T_{STG}	-65 ~ +150	°C

Electrical Characteristics(KA78L05AA) (Continued)

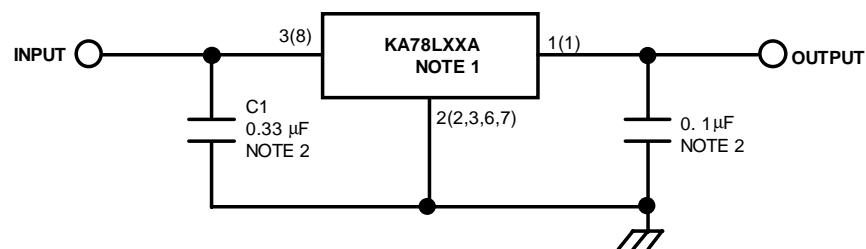
($V_I = 10V$, $I_O = 40mA$, $0^\circ C \leq T_J \leq 125^\circ C$, $C_I = 0.33 \mu F$, $C_O = 0.1 \mu F$, unless otherwise specified. (Note 1)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	$T_J = 25^\circ C$		4.9	5.0	5.1	V
Line Regulation (Note1)	ΔV_O	$T_J = 25^\circ C$	$7V \leq V_I \leq 20V$	-	8	150	mV
			$8V \leq V_I \leq 20V$	-	6	100	mV
Load Regulation (Note1)	ΔV_O	$T_J = 25^\circ C$	$1mA \leq I_O \leq 100mA$	-	11	50	mV
			$1mA \leq I_O \leq 40mA$	-	5.0	25	mV
Output Voltage	V_O	$7V \leq V_I \leq 20V$	$1mA \leq I_O \leq 40mA$	-	-	5.15	V
		$7V \leq V_I \leq V_{MAX}$ (Note 2)	$1mA \leq I_O \leq 70mA$	4.85	-	5.15	V
Quiescent Current	I_Q	$T_J = 25^\circ C$		-	2.0	5.5	mA
Quiescent Current Change	with line	ΔI_Q	$8V \leq V_I \leq 20V$		-	-	1.5 mA
	with load	ΔI_Q	$1mA \leq I_O \leq 40 mA$		-	-	0.1 mA
Output Noise Voltage	V_N	$T_A = 25^\circ C$, $10Hz \leq f \leq 100kHz$		-	40	-	$\mu V/V_o$
Temperature Coefficient of V_O	$\Delta V_O/\Delta T$	$I_O = 5mA$		-	-0.65	-	$mV/^\circ C$
Ripple Rejection	RR	$f = 120Hz$, $8V \leq V_I \leq 18V$, $T_J = 25^\circ C$		41	80	-	dB
Dropout Voltage	V_D	$T_J = 25^\circ C$		-	1.7	-	V

Note:

1. The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.
2. Power dissipation $P_D \leq 0.75W$.

Typical Application



'()' : 8SOP Type

Notes:

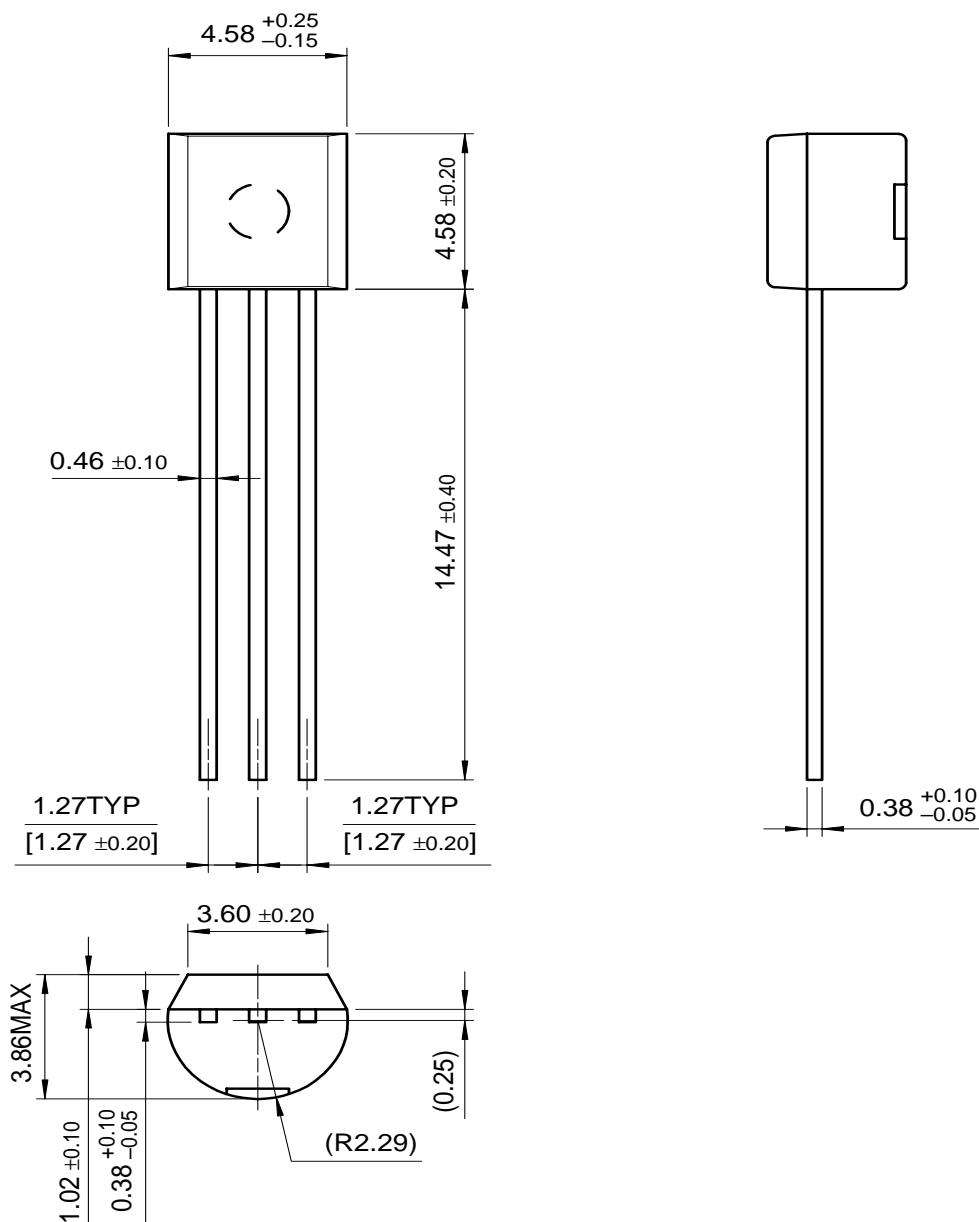
1. To specify an output voltage, substitute voltage value for "XX".
2. Bypass Capacitors are recommended for optimum stability and transient response and should be located as close as possible to the regulator

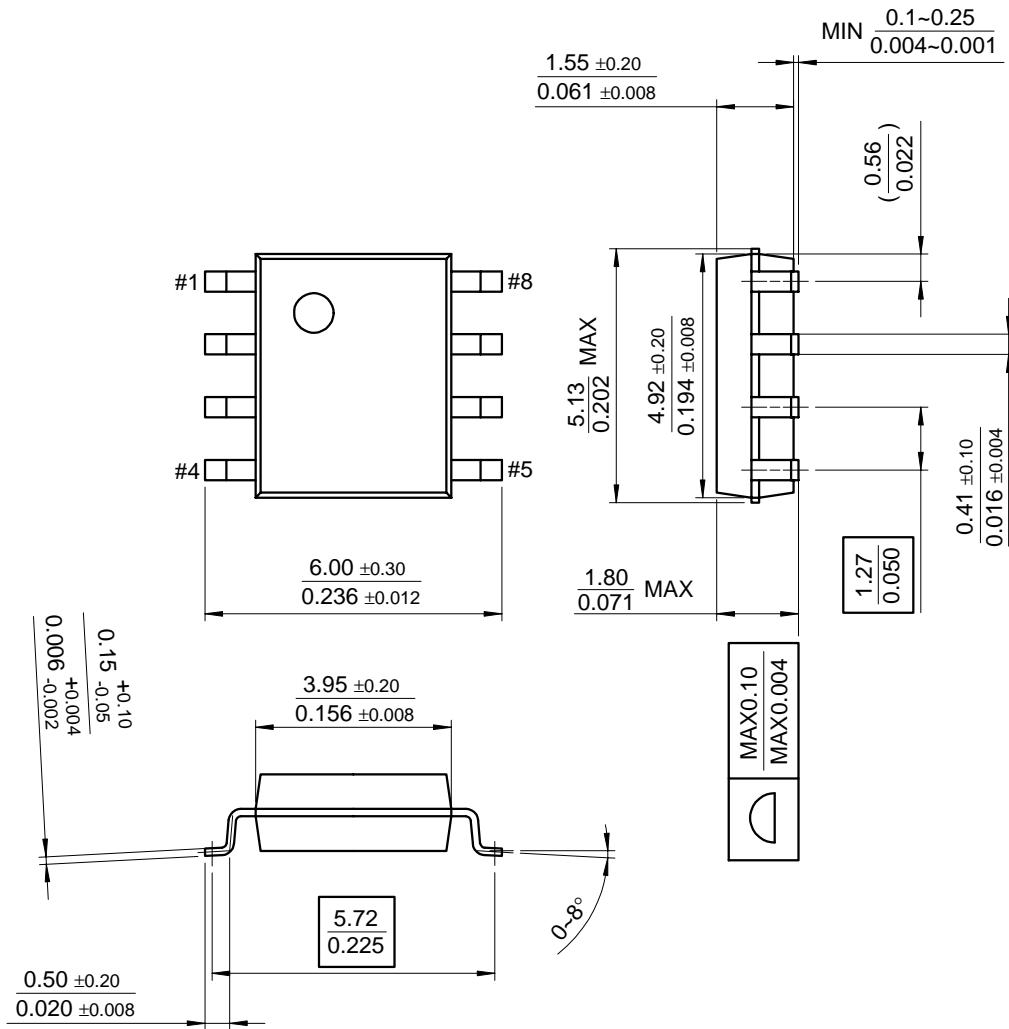
Mechanical Dimensions

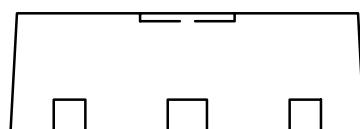
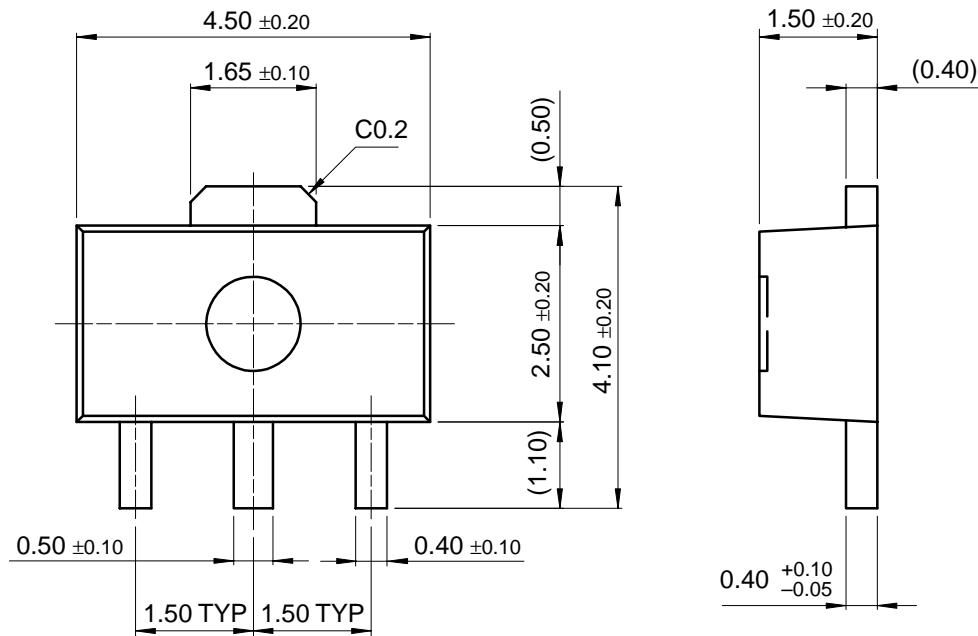
Package

Dimensions in millimeters

TO-92



Mechanical Dimensions (Continued)**Package****Dimensions in millimeters****8-SOP**

Mechanical Dimensions (Continued)**Package****Dimensions in millimeters****SOT-89**

Ordering Information

Product Number	Package	Output Voltage Tolerance	Operating Temperature
KA78L05AZ	TO-92	5%	0 ~ +125 °C
KA78L06AZ			
KA78L08AZ			
KA78L09AZ			
KA78L10AZ			
KA78L12AZ			
KA78L15AZ			
KA78L18AZ			
KA78L24AZ			
KA78L05AD			
KA78L08AD	8-SOP		
KA78L12AD			
KA78L05AM	SOT-89		
KA78L08AM			
KA78L12AM			
KA78L05AAZ	TO-92	2%	

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.